NSN 5961-00-410-8885

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-410-8885 **Inclosure Material:** Plastic **Overall Length:** 0.185 inches **Terminal Length:** 0.500 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 breakover voltage, dc **Current Rating Per Characteristic:** 2.00 amperes source cutoff current universal **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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